R&D Physique des particules (DRD)

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- Contexte
- · ECFA Détecteurs R&D Roadmap
- Projets DRD
- · Timescale

Inputs

- FCC week, Londres, 06/2023
- FCC physics workshop, Cracow, 01/2023
- Plenary ECFA, CERN, 11/2022
- 2nd DRD Calorimetry community meeting, CERN, 04/2023

Historique

- · Réunion orientée vers projets physique des particules (ECFA)
 - En particulier collisonneurs mais pas seulement (voir plus loin)
- Plusieurs discussions au Labo sur les futurs projets R&D
 - Biennale 2022
 - · Table ronde projets R&D : Petit embarqué, mécanique, Silicium pour accélérateurs, IA
 - · Projet FCC: Implication souhaitée dans calorimeter électromagnétique argon liquide
 - Réunion 'Prospectives techniques' (03/2023)
 - Réunions du vendredi
 - · Projet FCC avec discussion sur faisabilité CALICE/Argon liquide
- · En parallèle, montée en puissance des projets DRD (ECFA)
 - Discussions en Réunions de Coordination
- · -> Discussion (Marco, Didier, LP)
 - Suggestion d'organiser ½ journée d'information sur futurs projets R&D

ECFA R&D Roadmap CERN-ESU-017 (12/2021)

Moteur: Stratégie Européenne pour la Physique des Particules (2020)

physics programme in the near and long term". The particle physics programme mentioned here is taken to consist of the projects listed in the Deliberation Document of the European Particle Physics Strategy Update (EPPSU) [Ch0-2] as either "High-priority future initiatives" or "Other essential scientific activities for particle physics". The dif-

Mot-clé: Particules fondamentales

In the ECFA Detector R&D Roadmap the focus has been on facilities targeting the properties and interactions of fundamental particles (including those that are undiscovered but theoretically motivated). It is appreciated that a number of particles increas-

Facilités: Grands accélérateurs

Petits accélérateurs/Non-Acc



- Detector improvements required for full exploitation of the HL-LHC (R&D still needed for the next LHC Long Shutdown, LS3, upgrades and for experiment upgrades beyond then) including studies of flavour physics and quark-gluon plasma (where the latter topic also interfaces with nuclear physics);
- R&D for long baseline neutrino detectors (including aspects targeting astro-particle physics measurements) and supporting projects such as those at the CERN Neutrino Platform;
- Technology developments needed for detectors at e⁺e⁻ Higgs-EW-Top factories in all possible accelerator manifestations including instantaneous luminosities at 91.2 GeV of up to 5×10³⁶ cm⁻²s⁻¹ and energies up to the TeV range;
- The long-term R&D programme for detectors at a future 100 TeV hadron collider with integrated luminosities targeted up to 30 ab⁻¹ and 1000 multiple interactions for 25 ns bunch crossing interval;
- Specific long-term detector technology R&D requirements of a muon collider operating at 10 TeV and with a luminosity of the order of 10³⁵ cm⁻²s⁻¹;
- Detector developments for accelerator-based studies of rare processes, DM candidates and high precision measurements (including strong interaction physics) at both storage rings and fixed target facilities, interfacing also with atomic and nuclear physics;
- R&D for optimal exploitation of dedicated collider experiments studying the partonic structure of the proton and nuclei as well as interface areas with nuclear physics;
- The very broad detector R&D areas for non-accelerator-based experiments, including dark matter searches (including axion searches), reactor neutrino experiments and rare decay processes, also considering neutrino observatories and other interface areas with astro-particle physics.

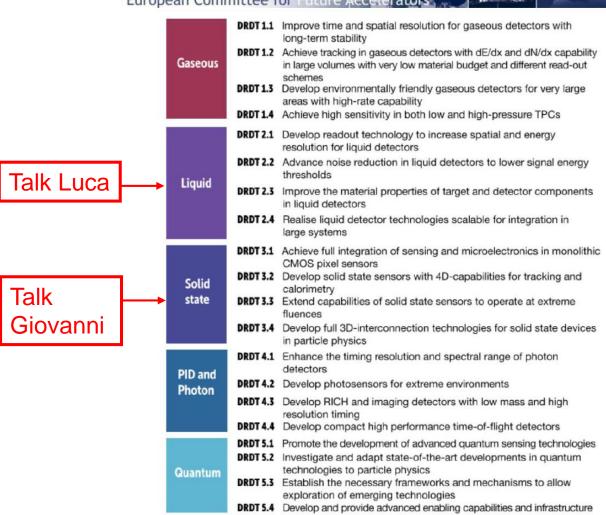


Axes R&D

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Organisation projets DRD: Tracks

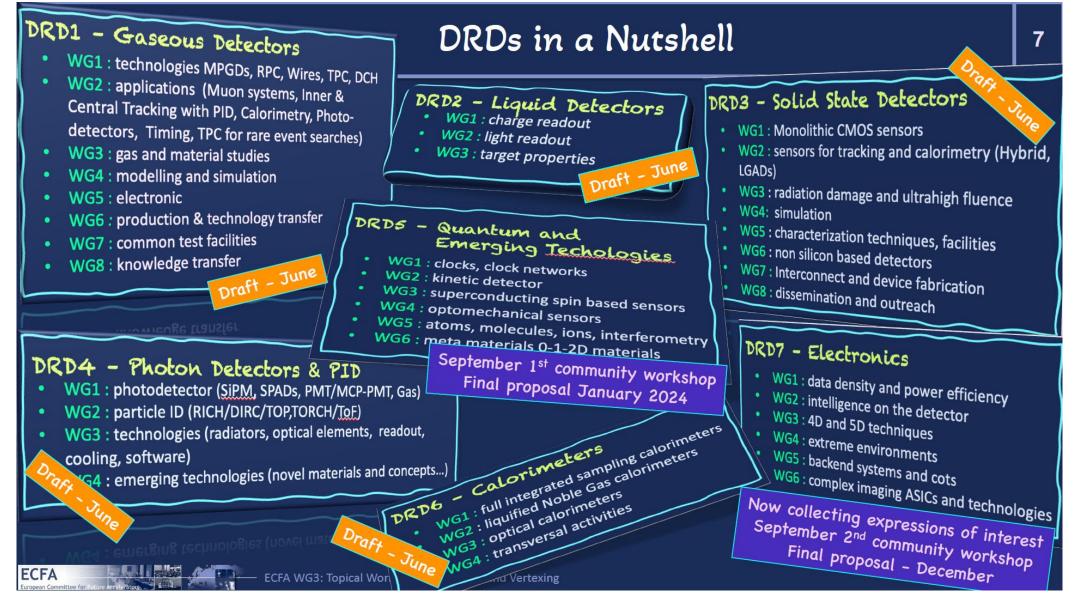




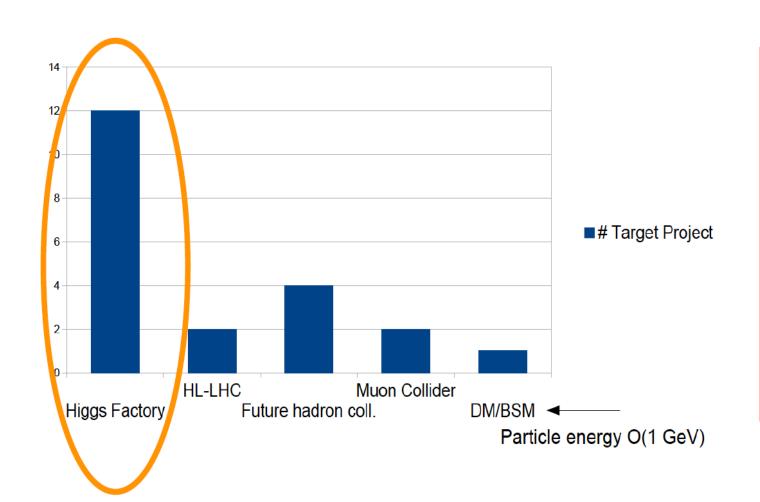
- The most urgent R&D topics in each Task Force area are identified as Detector R&D Themes.
- The timeframe illustration for requirements in each DRDT area, in both the brochure and the main document, are based on the more detailed information and charts in the individual chapters.

	DRDT 6.1	Develop radiation-hard calorimeters with enhanced electromagnetic energy and timing resolution	Talks
Calorimetry	DRDT 6.2	Develop high-granular calorimeters with multi-dimensional readout for optimised use of particle flow methods	
	DRDT 6.3	Develop calorimeters for extreme radiation, rate and pile-up environments	Rémi, LP
	DRDT 7.1	Advance technologies to deal with greatly increased data density	Tolk
	DRDT 7.2	Develop technologies for increased intelligence on the detector	Talk
Electronics	DRDT 7.3	Develop technologies in support of 4D- and 5D-techniques	Francesco
	DRDT 7.4	Develop novel technologies to cope with extreme environments and required longevity	Trancesco
	DRDT 7.5	Evaluate and adapt to emerging electronics and data processing technologies	
	DRDT 8.1	Develop novel magnet systems	
	DRDT 8.2	Develop improved technologies and systems for cooling	
Integration	DRDT 8.3	Adapt novel materials to achieve ultralight, stable and high precision mechanical structures. Develop Machine Detector Interfaces.	
	DRDT 8.4	Adapt and advance state-of-the-art systems in monitoring including environmental, radiation and beam aspects	
Training	DCT1	Establish and maintain a European coordinated programme for training in instrumentation	
	DCT 2	Develop a master's degree programme in instrumentation	

Organisation projets DRD: Working Groups



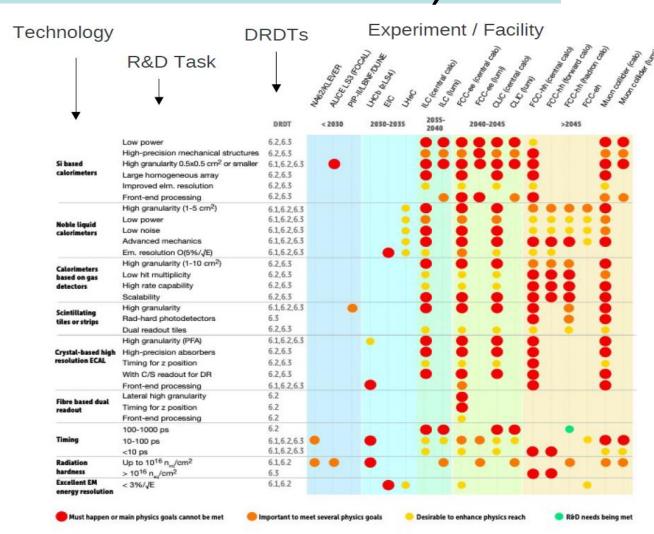
Projets futurs couverts par DRD (Exemple Calorimétrie DRD6)



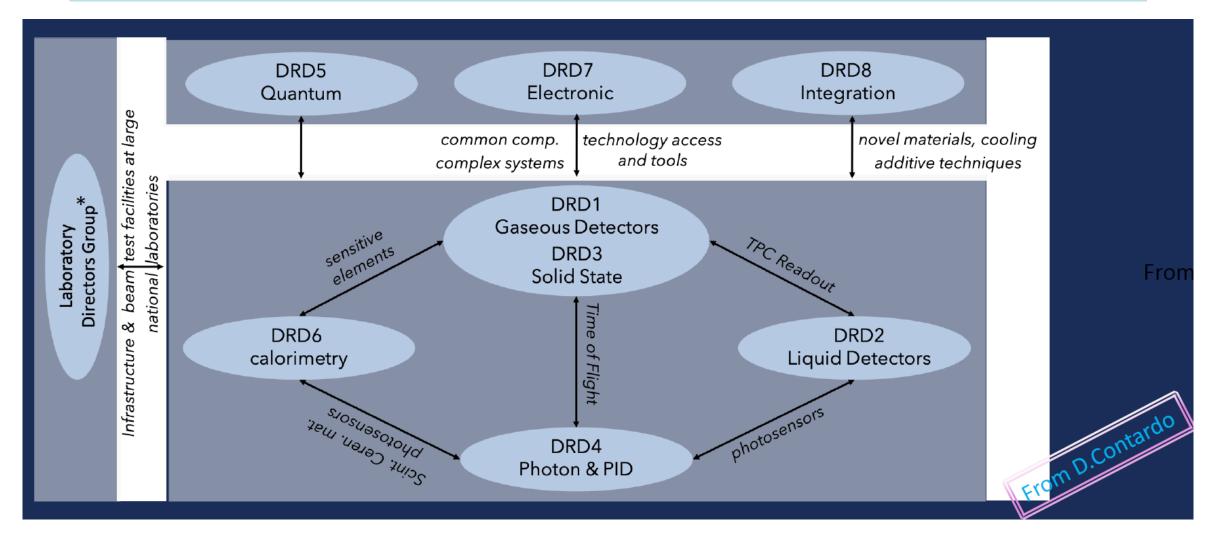
- En majorité, projets pour future usine à Higgs (FCC-ee, C3, ILC, CEPC)
- Aussi autres collisionneurs (FCC-hh, Muon Collider
- Aussi Matière Noire/BSM

DRD: Tâches vs Projets (exemple Calorimétrie DRD6)

- Key technologies and requirements identified in roadmap
 - · Si based calorimeters
 - Liquid Noble Gas calorimeters
 - Calorimeters based on gas detectors
 - Scintillating tiles and strips
 - Crystal based high-resolution ECal.s
 - Fibre-based dual readout
- R&D should in particular enable
 - Precision timing
 - Radiation hardness
 - High granularity
- R&D Tasks grouped into
 - Must happen
 - Important
 - Desirable
 - Already met



Interplay entre différents DRD (exemple DRD3/DRD1)



Detecteurs: R&D collaborations

RD1 SPACAL RD3 LAr calo RD50 Silicium RD53 Silicium

Follow the successful model of R&D collaborations for the LHC

- funding in place since ~1986, R&D collaborations established in 1990
- Aim at few large DRD collaborations, to keep it manageable

Take full account of existing, successful and well managed R&D coll.

Integrate with CERN EP R&D, AIDAinnova, RDxy, CALICE,....

Community-driven approach, supported by ECFA Roadmap Task Forces

invite proposals, moderate process, timeline 1-2 years

Reasonably dimensioned review process (ECFA and CERN)

- addressing needs of future experiments is important criterion
- worldwide perspective

R&D Détecteurs: Revue & Approbation

Scientific and Resource Reporting and Review by a Detector Research and Development Committee (DRDC)

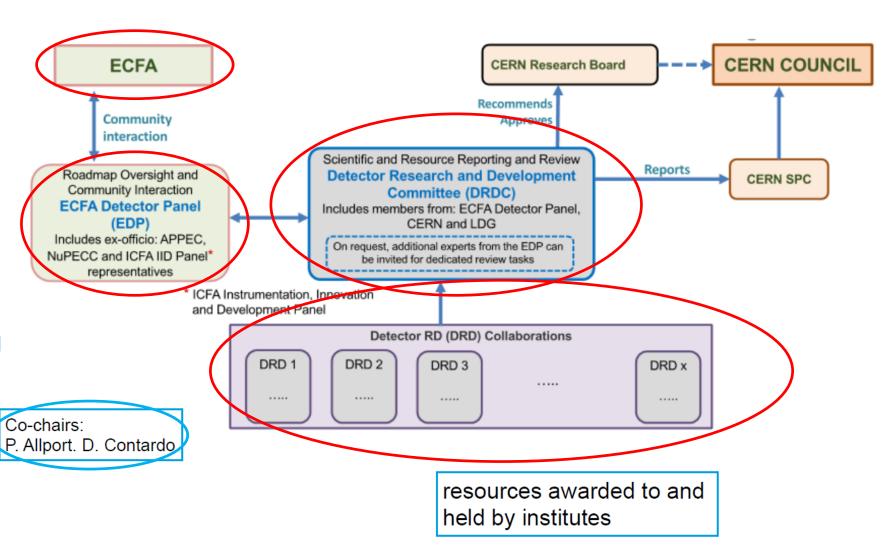
- yearly follow-up
- report via SPC to Council

Assisted by the ECFA Detector Panel (EDP):

- the scope, R&D goals, and milestones should be vetted against the vision encapsulated in the Roadmap.
- EDP exists, hosted at DESY: <u>http://cds.cern.ch/record/</u> 2211641/files/

Funding Agency involvement via a dedicated Resources Review Board

· once every two years



R&D Détecteurs: Implementation timeline

Goal: Transition to new scheme during 2023

approval of LHC-oriented RD50 (silicon), RD51 (gas detector) collaborations expires Dec 2023

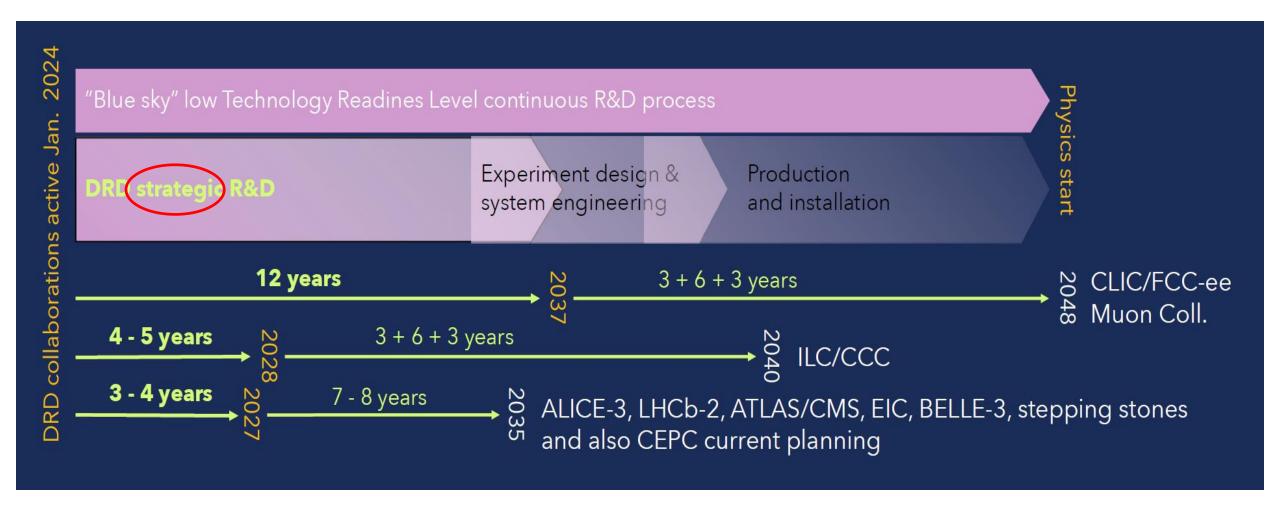
Major Steps:

- community input (via existing R&D bodies where possible) by Q1 2023
 - To get involved, register at https://indico.cern.ch/event/957057/page/27294-implementation-of-the-ecfa-detector-rd-roadmap
- Work Package structure (Tasks, Participants, Resources, Deliverables, Milestones) by spring 2023
- In parallel, **DRDC** mandate and membership defined
- Written proposals, based on ECFA Detector Roadmap, by mid 2023
 - do not repeat roadmap; concrete plans, deliverables, resource-loaded (not a wish list) for period 2024-2030
 - aim at 20 pages per each of 9 the DRDs (or not much more)
- Review (by DRDC, assisted by EDP) in fall 23, approval by end 2023
- R&D collaborations operational, "Grant Agreements" (MoU signatures) through 2024

Challenge

- funding not exactly known but cost projections should be backed by Funding Agencies
- interaction with Agencies needed in parallel to proposal preparation

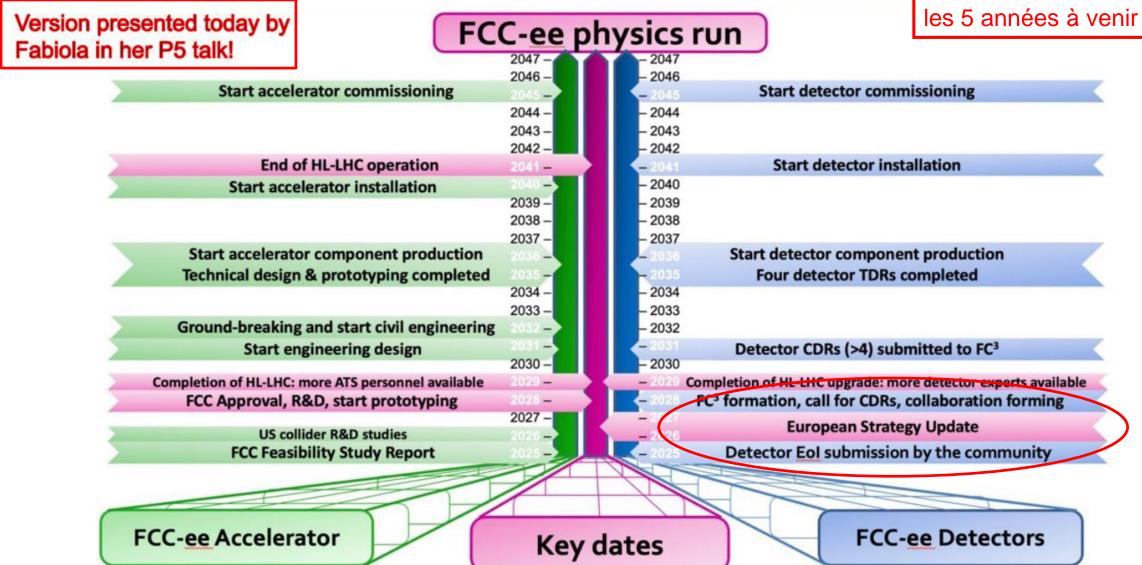
Futurs projets & Timescale DRD



Timeline FCC-ee

Échéances cruciales wrt Détecteurs dans les 5 années à venir

13



Aujourd'hui

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14:00 → 14:10	Introduction Orateur: Marco Zito (LPNHE)	③10m 🗷 🔻			
14:10 → 14:30	Situation générale Orateur: Luc Poggioli (LPNHE Paris)	③ 20m 			
14:30 → 14:50	DRD3 : Détecteurs silicium Orateur: Giovanni Calderini (LPNHE Paris)	③ 20m ☑ ▼			
14:50 → 15:10	DRD6 : Calorimétrie silicium Orateur: Dr Rémi CORNAT (LPNHE, Sorbonne Université - CNRS/IN2P3)	③ 20m 🕝 🕶			
15:10 → 15:30	DRD6 : Calorimétrie liquides nobles Orateur: Luc Poggioli (LPNHE Paris)	③ 20m 🗷 🔻			
15:30 → 15:50	DRD7 : Electronique Orateur: Francesco Crescioli (LPNHE)	③ 20m 🗷 🔻			
15:50 → 16:10	DRD2 : Détecteurs liquides Orateur: Luca Scotto Lavina (LPNHE Paris)	③ 20m ☑ ▼			
16:10 → 16:55	Discussion	③ 45m ② ▼			

Backup

ECFA R&D Roadmap (2)



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ECFA R&D Roadmap (3)



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Process from May 2020 to December 2021 involved: 67 authors; 12 expert Input Session speakers; ECFA National Contacts; Correspondents to the Task Force surveys; 121 Symposia presenters; 1359 Symposia attendees and 44 APOD* TF topic specific contacts.

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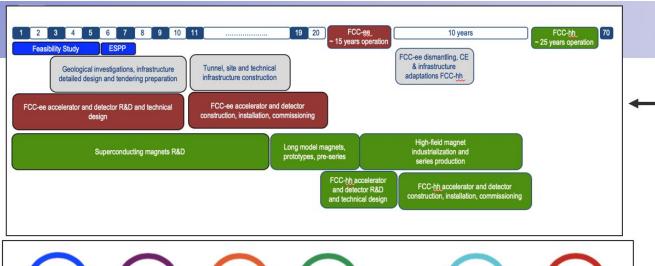
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Timescale Grands Projets (eg FCC-ee)



FCC estimated timeline

F. Gianotti London 06/2023

Technical schedule:

FCC-ee could start physics operation in 2040 or earlier



- past experience in building colliders at CERN
- approval timeline: ESPP, Council decision
- ☐ that HL-LHC will run until ~ 2041
- → ANY future collider at CERN cannot start physics operation before ~ 2045 (but construction will proceed in parallel to HL-LHC operation)

~2070 2018 2025 2048 ~2041 HL-LHC Conceptual Design Feasibility Study Project approval by Operation of FCC-ee Operation of FCC-hh Construction of ends (geology, R&D on accelerator, (15 years physics exploitation) (~20 years of physics exploitation) **CERN Council** tunnel and FCC-ee (Conceptual Design Report technologies, administrative starts procedures with the Host States, environmental impact, financial

1st stage collider, FCC-ee: electron-positron collisions 90-360 GeV

Construction: 2033-2045 → Physics operation: 2048-2063

2nd **stage collider, FCC-hh**: proton-proton collisions at ≥ 100 TeV

Construction: 2058-2070 → Physics operation: ~ 2070-2095

Care should be taken when comparing to other proposed facilities, for which in some cases only the (optimistic) technical schedule is shown

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